CZT3904 NPN
CZT3906 PNP

SURFACE MOUNT
COMPLEMENTARY
SILICON TRANSISTORS



SOT-223 CASE

Central Semiconductor Corp.

www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CZT3904, CZT3906 types are complementary silicon transistors manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for small signal general purpose and switching applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T_A=25°C)

	SYMBOL	CZT3904	CZT3906	UNITS
Collector-Base Voltage	V_{CBO}	60	40	V
Collector-Emitter Voltage	V_{CEO}	40	40	V
Emitter-Base Voltage	V_{EBO}	6.0	5.0	V
Continuous Collector Current	I_C	200		mA
Power Dissipation	P_D	2.0		W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150		°C
Thermal Resistance	Θ_{JA}	62.5		°C/W

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

		CZT3904		CZT3906		
SYMBOL	**TEST CONDITIONS**	**MIN**	**MAX**	**MIN**	**MAX**	**UNITS**
I_{CEV}	V_{CE}=30V, V_{EB}=3.0V	-	50	-	50	nA
BV_{CBO}	I_C=10μA	60	-	40	-	V
BV_{CEO}	I_C=1.0mA	40	-	40	-	V
BV_{EBO}	I_E=10μA	6.0	-	5.0	-	V
$V_{CE(SAT)}$	I_C=10mA, I_B=1.0mA	-	0.20	-	0.25	V
$V_{CE(SAT)}$	I_C=50mA, I_B=5.0mA	-	0.30	-	0.40	V
$V_{BE(SAT)}$	I_C=10mA, I_B=1.0mA	0.65	0.85	0.65	0.85	V
$V_{BE(SAT)}$	I_C=50mA, I_B=5.0mA	-	0.95	-	0.95	V
h_{FE}	V_{CE}=1.0V, I_C=0.1mA	40	-	60	-	
h_{FE}	V_{CE}=1.0V, I_C=1.0mA	70	-	80	-	
h_{FE}	V_{CE}=1.0V, I_C=10mA	100	300	100	300	
h_{FE}	V_{CE}=1.0V, I_C=50mA	60	-	60	-	
h_{FE}	V_{CE}=1.0V, I_C=100mA	30	-	30	-	
f_T	V_{CE}=20V, I_C=10mA, f=100MHz	300	-	250	-	MHz
C_{ob}	V_{CB}=5.0V, I_E=0, f=1.0MHz	-	4.0	-	4.5	pF
C_{ib}	V_{BE}=0.5V, I_C=0, f=1.0MHz	-	8.0	-	10	pF
h_{ie}	V_{CE}=10V, I_C=1.0mA, f=1.0kHz	1.0	10	2.0	12	kΩ

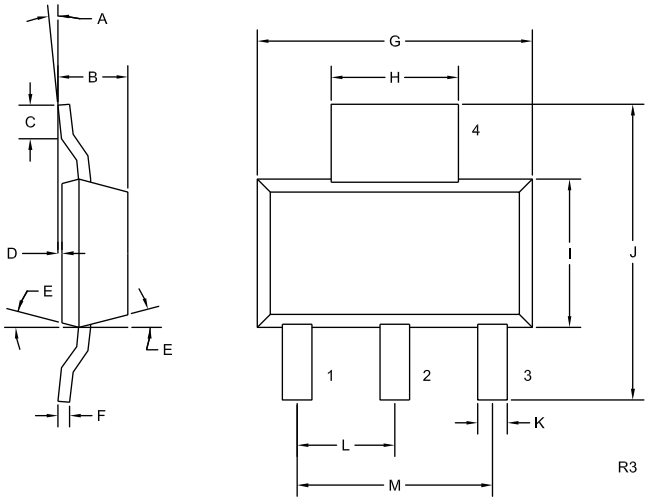
R5 (1-March 2010)

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ELECTRICAL CHARACTERISTICS - Continued: (T_A=25°C)		**CZT3904**		**CZT3906**		
SYMBOL	**TEST CONDITIONS**	**MIN**	**MAX**	**MIN**	**MAX**	**UNITS**
h_{re}	V_{CE}=10V, I_C=1.0mA, f=1.0kHz	0.5	8.0	0.1	10	x10^{-4}
h_{fe}	V_{CE}=10V, I_C=1.0mA, f=1.0kHz	100	400	100	400	
h_{oe}	V_{CE}=10V, I_C=1.0mA, f=1.0kHz	1.0	40	3.0	60	μS
NF	V_{CE}=5.0V, I_C=100μA, R_S=1.0kΩ					
	f=10Hz to 15.7kHz	-	5.0	-	4.0	dB
t_d	V_{CC}=3.0V, V_{BE}=0.5V, I_C=10mA, I_{B1}=1.0mA	-	35	-	35	ns
t_r	V_{CC}=3.0V, V_{BE}=0.5V, I_C=10mA, I_{B1}=1.0mA	-	35	-	35	ns
t_s	V_{CC}=3.0V, I_C=10mA, I_{B1}=I_{B2}=1.0mA	-	200	-	225	ns
t_f	V_{CC}=3.0V, I_C=10mA, I_{B1}=I_{B2}=1.0mA	-	50	-	75	ns

SOT-223 CASE - MECHANICAL OUTLINE



DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
A	0°	10°	0°	10°
B	0.059	0.071	1.50	1.80
C	0.018	---	0.45	---
D	0.000	0.004	0.00	0.10
E	15°		15°	
F	0.009	0.014	0.23	0.35
G	0.248	0.264	6.30	6.70
H	0.114	0.122	2.90	3.10
I	0.130	0.146	3.30	3.70
J	0.264	0.287	6.70	7.30
K	0.024	0.033	0.60	0.85
L	0.091		2.30	
M	0.181		4.60	

SOT-223 (REV: R3)

LEAD CODE:
1) Base
2) Collector
3) Emitter
4) Collector

MARKING:
FULL PART NUMBER